## HL 55: Electronic-Structure Theory: New Concepts and Developments in Density Functional Theory and Beyond - IV

Time: Wednesday 10:30-13:00

Invited TalkHL 55.1Wed 10:30GER 38Electronic excitations in 2D materials and heterostructures —•KRISTIAN SOMMER THYGESEN — Technical University of Denmark,<br/>Lyngby, Denmark

Atomically thin two-dimensional (2D) materials have recently emerged as a new class of materials with unique and highly tunable optoelectronic properties. Different 2D crystals can be stacked to form van der Waals heterostructures (vdWH) where the individual 2D layers are held together by weak van der Waals forces leading to atomically well-defined interfaces. This fascinating scenario opens up the possibility of designing heterostructures with tailored electronic or optical properties. I will give a general introduction to the electronic properties of 2D materials, including characteristic features of their dielectric screening and collective excitations with special emphasis on the challenges related to their ab-initio description. I will show how the dielectric function of a given 2D material can be controlled by embedding it into a vdWH, and how this in turn can be used to control the band structure, exciton binding energies or the plasmon dispersion in 2D materials.

HL 55.2 Wed 11:00 GER 38 Charge and energy transport at the nanoscale: A DFT perspective — •FLORIAN G. EICH, FABIO COVITO, and ANGEL RUBIO — Max Planck Institute for the Structure and Dynamics of Matter, Luruper Chaussee 149, D-22761 Hamburg, Germany

Understanding the interplay between charge and energy transport at the nanoscale paves the way for novel thermoelectric devices, which may prove useful for the development for sustainable energy sources. However, concepts, such as heat flow, temperature and entropy are only well-established at the macroscopic level for slow dynamics. This raises the question about whether these concepts can be employed for small length and short time scales. We will present our recent efforts to use a time-dependent density-functional theory framework, dubbed nonequilibrium thermal DFT, in order to generalize temperature and heat or energy flow to the microscopic regime. To this end we will highlight the analogy of the formally exact microscopic equations of motion for charge density and energy density in thermal DFT to the macroscopic equations of motion of hydrodynamics. Furthermore, we will present first result using our approach to compute transient energy energy currents induced by a temperature gradient and show that in the steady-state limit persistent temperature oscillations develop.

## HL 55.3 Wed 11:15 GER 38

Conductance of aromatic and antiaromatic molecular circuits — NARENDRA P. ARASU and •HÉCTOR VÁZQUEZ — Inst. of Physics, Academy of Sciences of the Czech Rep., CZ

Molecular structures with delocalized conjugated orbitals play an essential role in molecular transport due to their high conductance and small attenuation factors. While much work has been done on aromatic molecules, some studies have shown that conductance actually decreases with aromaticity [1].

In this talk I will discuss the effect of (anti)aromaticity on conductance. I will show results of first-principles transport calculations for an aromatic-antiaromatic pair of molecules and compare with experiment. Conductance is calculated using DFT and NEGF including corrections to the DFT level positions. The corrected conductance values are in very good agreement with experiment. We find that the conductance of the antiaromatic molecule is much higher than that of its aromatic counterpart. Calculations show this to be a consequence of the smaller HOMO-LUMO gap of the antiaromatic complex as well as on the molecular level alignment at the junction [2].

[1] W. Chen, H. Li, J.R. Widawsky, C. Appayee, L. Venkataraman, and R. Breslow, J. Am. Chem. Soc. 136 918 (2014).

[2] S. Marqués-González, S. Fujii, J.-Y. Shin, H. Shinokubo, N.P. Arasu, H. Vázquez and M. Kiguchi, (to be submitted).

## HL 55.4 Wed 11:30 GER 38

Current-induced cooling of Carbene-based molecular junctions: role of electrodes structure — •GIUSEPPE FOTI and HÉC-TOR VÁZQUEZ — Institute of Physics, Czech Academy of Sciences Cukrovarnicka 10, Prague 6 Location: GER 38

In this talk I will present our first principles calculations based on density functional theory (DFT) plus Nonequilibrium Green's functions (NEGF) of the current-induced heating and cooling dynamics of a series of Carbene-based molecular junctions [1]. I will show how the atomistic details of electrode terminations have a strong impact on the heating dynamics of the junctions and how they can maximize the cooling of the system. In the cases where the molecule is attached to blunt leads and the electronic coupling to bulk states is strong the cooling efficiency of the most active vibrational modes decreases monotonically as bias increases. This results in the heating of the junction. On the other hand, when the molecule is connected to sharp electrode terminations such as chain-like structures, which can be formed experimentally when the metal-molecule bond is mechanically strong, and the electronic coupling to electrode states is weak, the cooling efficiency shows a non-monotonic behavior. It first decreases as a function of voltage but then increases at relatively high biases, effectively cooling down the junction [2]. These results reveal the important role of the atomistic structure of metal-molecule interface in the current-induced damping of localized molecular vibrations.

[1] Foti, G.; Vázquez, H. Nanotechnology 2016, 27, 125702.

[2] Foti, G.; Vázquez, H. submitted

HL 55.5 Wed 11:45 GER 38 DFTB-based recursive Green's function algorithms for electron transport in quasi-1D systems — •FABIAN TEICHERT<sup>1,2,4</sup>, ANDREAS ZIENERT<sup>3,4</sup>, JÖRG SCHUSTER<sup>4</sup>, and MICHAEL SCHREIBER<sup>2</sup> — <sup>1</sup>Dresden Center for Computational Materials Science (DCMS), Dresden, Germany — <sup>2</sup>Institute of Physics, Technische Universität Chemnitz, Chemnitz, Germany — <sup>3</sup>Center for Microtechnologies (ZfM), Technische Universität Chemnitz, Chemnitz, Germany — <sup>4</sup>Fraunhofer Institute for Electronic Nano Systems (ENAS), Chemnitz, Germany

Within the last decades, quantum transport theory and density functional theory have become very important for predicting the electronic properties of new materials and future electronic devices.

We focus on the problem of improving quantum transport algorithms for large quasi-1D systems which are enormously time-consuming today. We combine the density functional tight binding (DFTB) approach with the recursive Green's function formalism (RGF), which is very effective for such systems. First, we show how to improve the RGF for the case of randomly distributed real defects. For this, we use the steps of the renormalization decimation algorithm (RDA), which is part of the electrode calculation. Second, we show how to improve the calculation of the surface Green's functions of electrodes which have a long unit cell. Here, we employ the decimation technique to reduce the dimensionality of the periodic Hamiltonian matrix, leading to effective matrices, which are treated by the RDA. Finally, we apply these algorithms to carbon nanotubes and present our results.

HL 55.6 Wed 12:00 GER 38

Conditions for formation of two-dimensional electron gas at the LaFeO<sub>3</sub>/SrTiO<sub>3</sub> — •IGOR MAZNICHENKO<sup>1</sup>, SERGEY OSTANIN<sup>1</sup>, ARTHUR ERNST<sup>2</sup>, INGRID MERTIG<sup>1,2</sup>, KATAYOON MOHSENI<sup>2</sup>, HOLGER L. MEYERHEIM<sup>2</sup>, EBERHARD K.U. GROSS<sup>2</sup>, PENGFA XU<sup>3</sup>, WEI HAN<sup>3</sup>, PHILIP M. RICE<sup>3</sup>, JAEWOO JEONG<sup>3</sup>, MAHESH G. SAMANT<sup>3</sup>, and STUART S.P. PARKIN<sup>2,3</sup> — <sup>1</sup>Institut für Physik, Martin-Luther-Universität Halle-Wittenberg, D-06099 Halle, Germany — <sup>2</sup>Max-Planck-Institut für Mikrostrukturphysik, Weinberg 2, D-06120 Halle, Germany — <sup>3</sup>IBM Almaden Research Center, 650 Harry Road, San Jose, California 95120, USA

The formation of a conducting two dimensional electron gas (2DEG) at the interface between two insulating oxide layers was explained theoretically for atomically and chemically abrupt interfaces via polar discontinuity.

Here we show that a 2DEG is formed at the interface between thin layers of lanthanum ferrite, LaFeO<sub>3</sub> (LFO), that are more than 3 unit cells thick, when grown epitaxially on  $SrTiO_3$  (STO) (001). The interface property highly depends on the surface property of TiO<sub>2</sub> terminated STO. The interface is conducting if the STO is not annealed in an oxygen environment prior to the LFO growth, while insulating if the STO is annealed.

First principles calculations reveal that a 2DEG should be realized for an ideal interface but that modest chemical intermixing suppresses it. These calculations also show that the presence of oxygen vacancies supports 2DEG formation due to electronic doping.

## HL 55.7 Wed 12:15 GER 38

**Thermal Renormalization of the Electronic Structure: Trends across Chemical and Structural Space** — •HONGHUI SHANG<sup>1</sup>, CHRISTIAN CARBOGNO<sup>1</sup>, PATRICK RINKE<sup>2</sup>, and MATTHIAS SCHEFFLER<sup>1</sup> — <sup>1</sup>Fritz-Haber-Institut der Max-Planck-Gesellschaft, Berlin — <sup>2</sup>Aalto University, Helsinki, Finland

Advances in electronic structure theory now allow us to compute the renormalization of the electronic structure due to thermal nuclear motion from first principles [1]. In this work, we present a systematic computational assessment of this renormalization for 82 octet binaries in both the zincblende and the rocksalt structure. After validating our computational approach that is based on finite-differences [2] and Fröhlich-type corrections [3] for polar materials, we discuss and analyze the observed trends: For instance, we find that most materials exhibit the expected band-gap reduction upon temperature increase; however, some materials (e.g. CuCl and CdO) do not follow this trend and exhibit the opposite behavior. We discuss the underlying electronic mechanism as well as its dependence on the chemical composition and structure of the material. In this context, also the sensitivity of such calculations with respect to the chosen basis set and exchangecorrelation functional (LDA, PBE, HSE06) are critically investigated. [1] F. Giustino, arXiv:1603.06965 (2016).

[2] G. Antonius, et al. Phys. Rev. Lett. 112, 215501 (2014).

[3] J. P. Nery and P. B. Allen, *Phys. Rev. B* **94**, 115135 (2016).

HL 55.8 Wed 12:30 GER 38

Spin-wave excitations and electron-magnon scattering from many-body perturbation theory — •MATHIAS C.T.D. MÜLLER, CHRISTOPH FRIEDRICH, and STEFAN BLÜGEL — Peter Grünberg Institut and Institute for Advanced Simulation, Forschungszentrum Jülich and JARA, 52425 Jülich, Germany

We study the spin excitations and the electron-magnon scattering in bulk Fe, Co, and Ni within the framework of many-body perturbation theory as implemented in the full-potential linearized augmentedplane-wave method. Starting from the GW approximation we obtain a Bethe-Salpeter equation for the magnetic susceptibility treating singleparticle Stoner excitations and magnons on the same footing. Due to approximations used in the numerical scheme, the acoustic magnon dispersion exhibits a small but finite gap at  $\Gamma$ . We analyze this violation of the Goldstone theorem and present an approach that implements the magnetic susceptibility using a renormalized Green function instead of the non-interacting one, leading to a substantial improvement of the Goldstone-mode condition [1]. Finally, we employ the solution of the Bethe-Salpeter equation to construct a self-energy that describes the scattering of electrons and magnons. The resulting renormalized band structures exhibit strong spin-dependent lifetime effects close to the Fermi energy. We also see kinks in the electronic bands, which we attribute to electron scattering with spatially extended spin waves. [1] Müller *et al.*, Phys. Rev. B **94**, 064433 (2016).

HL 55.9 Wed 12:45 GER 38 Charged supercells revised: Small Polarons in Oxides with proper account for long-range polarization — •Sebastian Kokott, Sergey V. Levchenko, and Matthias Scheffler — Fritz-Haber-Institut der MPG, Berlin, DE

Formation of small polarons (excess charges localized within one unit cell) often determines charge mobility and optical absorption in oxide materials. In this work, we address two important challenges in the DFT description of small polarons: sensitivity to the errors in exchange-correlation (XC) treatment and finite-size effects in supercell calculations. The polaron properties are obtained using a modified neutral potential-energy surface (PES) [1]. Using the hybrid HSE functional and considering the whole range  $0 \le \alpha \le 1$  of exact exchange, we show that the modified PES model significantly reduces the dependence of the polaron level and binding energy in MgO and  $TiO_2$  on the XC treatment. It does not eliminate the dependence on supercell size. Based on Pekar's model [2], we derive the proper longrange behavior of the polaron and a correction that allows to obtain the polaron properties in the dilute limit (tested for supercells containing up to 1,000 atoms). The developed approach reduces drastically the computational time for exploring the polaron PES, and gives a consistent description of polarons for the whole range of  $\alpha$ . It allows us to find a self-trapped hole in MgO that is noticeably more stable than reported previously.-[1] B. Sadigh et al., PRB 92, 075202 (2015); [2] S.I. Pekar, ZETF 16, 335 (1946). This work received funding from the Leibniz ScienceCampus "GraFOx".